

## Supporting Information

### **Panchromatic Light Harvesting by N719 with a Porphyrin Molecule for High-Performance Dye-Sensitized Solar Cells**

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### Supporting Characterizations

**Table S1** Absorption wavelength, fluorescence maxima and porphyrin redox potentials of HD 18 in THF

Dyes	Absorption/ $\lambda_{\max}$ /nm ( $\epsilon, \times 10^5 \text{M}^{-1} \text{cm}^{-1}$ )	Emission $\lambda_{\max}$ /nm <sup>a</sup>	$E_{\text{ox}}/\text{V}^{\text{b}}$	$E_{0-0}/\text{V}^{\text{c}}$	$E_{\text{re}}/\text{V}^{\text{d}}$
HD18	456(1.67), 666(0.47)	679	+0.59, +0.80	1.74	-1.15

<sup>a</sup> Excitation wavelengths /nm: HD18, 456. <sup>b</sup> HOMO level was measured in THF with 0.1 M tetrabutylammonium hexafluorophosphate (TBAPF<sub>6</sub>). <sup>c</sup>  $E_{0-0}$  was estimated from the absorption threshold of dye in THF. <sup>d</sup> The LUMO was calculated using the equation LUMO = HOMO -  $E_{0-0}$ .

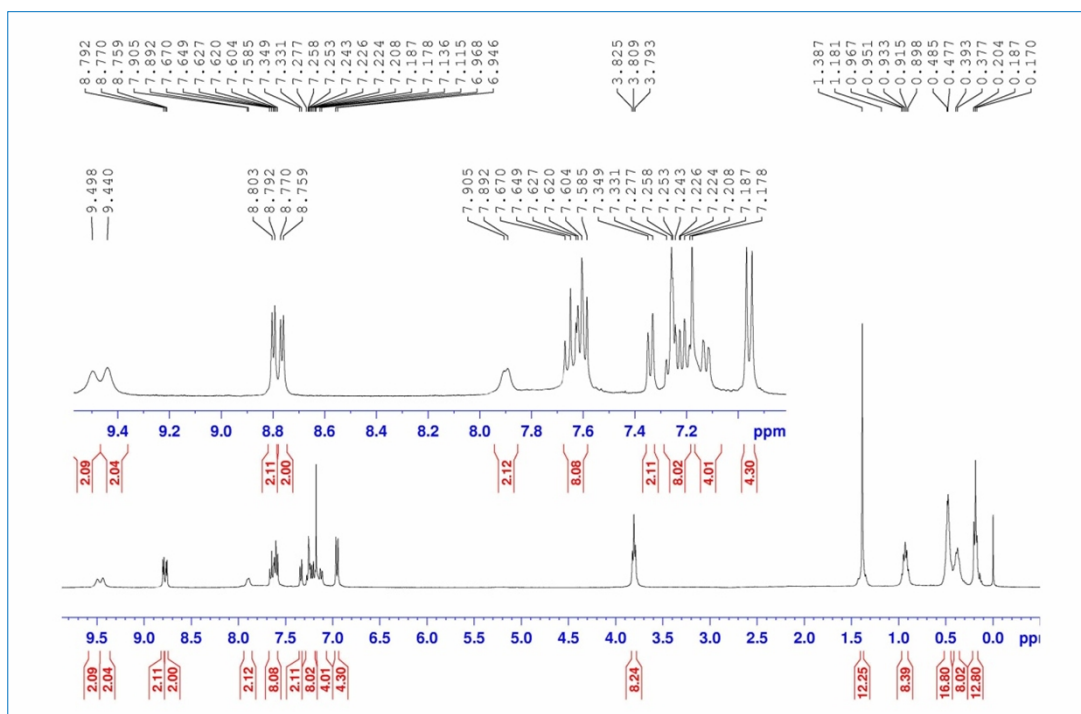


Fig. S1 <sup>1</sup>H NMR spectrum of HD18.

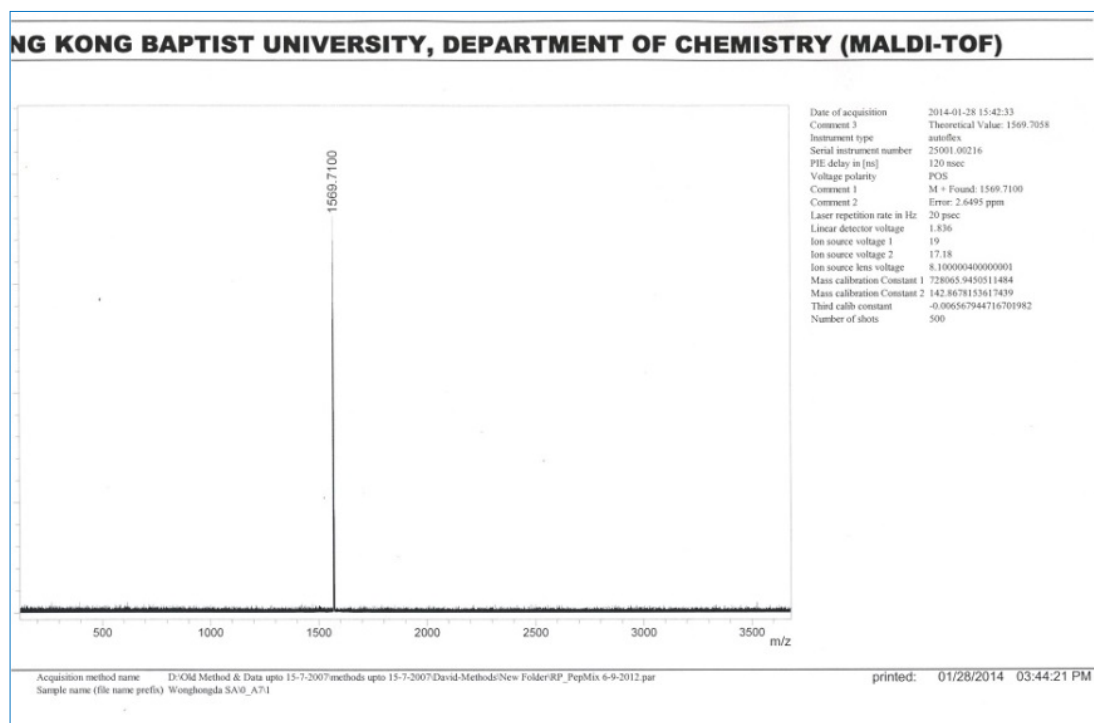
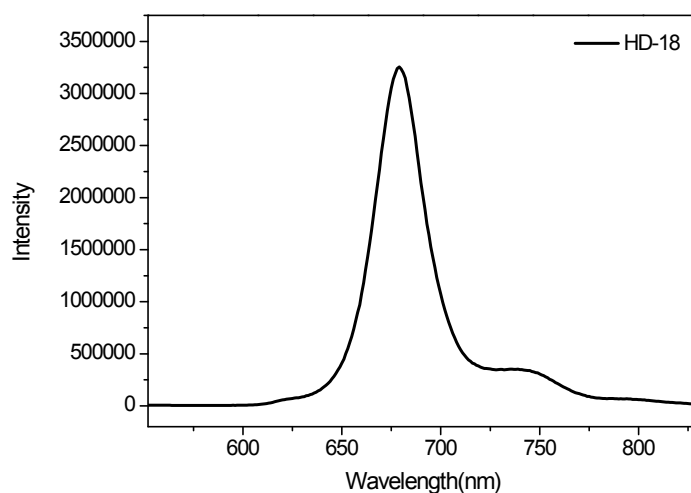
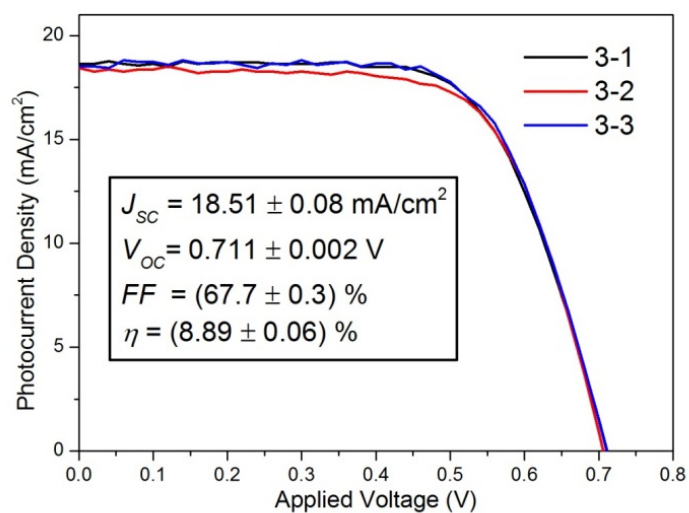


Fig. S2 ESI-HRMS of HD18.



**Fig. S3** Fluorescence spectra of HD18 measured in THF. Experimental conditions:  $1 \times 10^{-6}$  M.



**Fig. S4** Three identical co-sensitized devices denoted as 3-1, 3-2 and 3-3. The inset chart gives their average  $J_{sc}$ ,  $V_{oc}$ , fill factor ( $FF$ ) and PCE ( $\eta$ ) parameters with the margin of error.

**Table S2.** Simulated device parameters from the EIS data in Fig. 3a in main text

Device	$R_{CT}(\Omega)$	$f(\text{Hz})$	$\tau(\text{ms})$
<b>1</b>	52.2	32.56	4.89
<b>2</b>	196.4	10.30	15.45
<b>3</b>	142.1	13.01	12.23